NSN 5961-00-945-6090

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Inclosure	e Material:
Metal	
Overall L	_ength:
0.205 inc	hes
Terminal	I Length:
0.500 inc	hes
Overall [Diameter:
0.230 inc	hes
Internal	Configuration:
Unijunctio	on
Joint Ele	ectronic Device Engineering Council/jedec/case Outline Designation:
To-18	
Mounting	g Method:
Terminal	
Terminal	I Circle Diameter:
0.100 inc	hes
Features	Provided:
Hermetic	ally sealed case
Semicon	ductor Material:
Silicon	
Voltage I	Rating In Volts Per Characteristic:
30.0 emi	itter to base voltage, dc
Current I	Rating Per Characteristic:
50.00 mil	liamperes source cutoff current blank
Power R	ating Per Characteristic:
300.0 mil	liwatts small-signal input power, common-collector preset
Maximur	n Operating Tempurature Per Measurement Point:
100.0 deg	grees celsius junction
Terminal	Type And Quantity:
3 pin	
Shelf Life	e:
N/a	
Unit Of M	Neasure:
Demilita	rization:
No	
Fiig:	
A110a0	